

## IGBT

High speed DuoPack: IGBT in Trench and Fieldstop technology with soft, fast recovery anti-parallel diode

## IKW50N60H3

600V high speed switching series third generation

Data sheet

High speed IGBT in Trench and Fieldstop technology

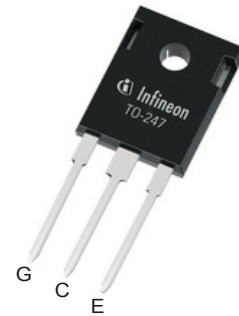
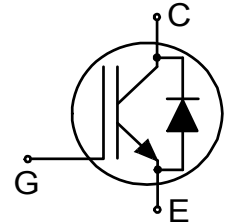
**Features:**

TRENCHSTOP™ technology offering

- very low  $V_{CEsat}$
- low EMI
- Very soft, fast recovery anti-parallel diode
- maximum junction temperature 175°C
- qualified according to JEDEC for target applications
- Pb-free lead plating; RoHS compliant
- complete product spectrum and PSpice Models:  
<http://www.infineon.com/igbt/>

**Applications:**

- uninterruptible power supplies
- welding converters
- converters with high switching frequency



**Key Performance and Package Parameters**

Type	$V_{CE}$	$I_C$	$V_{CEsat}, T_{vj}=25^{\circ}C$	$T_{vjmax}$	Marking	Package
IKW50N60H3	600V	50A	1.85V	175°C	K50H603	PG-TO247-3